

# RS4GT08 Quadruple 2-Input Positive-AND Gate

## 1 FEATURES

- **Operating Voltage Range: 2.0V to 5.5V**
- **Low Power Consumption: 1µA (Max)**
- **Operating Temperature Range: -40°C to +125°C**
- **Inputs Are TTL-Voltage Compatible**
- **High Output Drive: ±32mA at V<sub>CC</sub>=5.0V**
- **Micro SIZE PACKAGES: SOIC-14(SOP14), TSSOP14**

## 2 APPLICATIONS

- **Active Noise Elimination**
- **Bar Code Scanner**
- **Blood Pressure Monitor**
- **CPAP Machine**
- **Fingerprint identification**
- **Network attached storage (NAS)**

## 3 DESCRIPTIONS

The RS4GT08 quadruple 2-input positive-AND gate is designed for 2.0 to 5.5V V<sub>CC</sub> operation.

The RS4GT08 device performs the Boolean function  $Y=A \cdot B$  or  $Y= \overline{A} + \overline{B}$  in positive logic. The device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

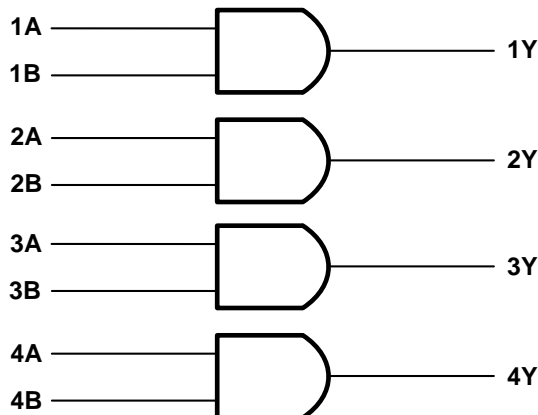
The RS4GT08 is available in Green SOIC-14(SOP14) and TSSOP-14 packages. It operates over an ambient temperature range of -40°C to +125°C.

### Device Information <sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
RS4GT08	SOIC-14 (SOP14)	8.65mm×3.90mm
	TSSOP14	5.00mm×4.40mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### LOGIC SYMBOL



## 4 FUNCTION TABLE

INPUTS		OUTPUT
A	B	Y
H	H	H
L	H	L
H	L	L
L	L	L

Y=A•B

H=High Voltage Level

L=Low Voltage Level

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## 5 Revision History

Note: Page numbers for previous revisions may differ from page numbers in the current version.

Version	Change Date	Change Item
A.1	2023/03/27	Initial version completed

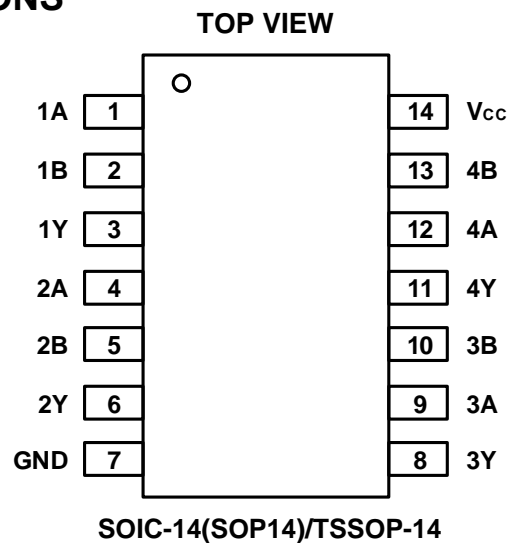
**6 PACKAGE/ORDERING INFORMATION <sup>(1)</sup>**

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING <sup>(2)</sup>	PACKAGE OPTION
RS4GT08	RS4GT08XP	-40°C ~+125°C	SOIC-14(SOP14)	RS4GT08	Tape and Reel,4000
	RS4GT08XQ	-40°C ~+125°C	TSSOP-14	RS4GT08	Tape and Reel,4000

## NOTE:

- (1) This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the right-hand navigation.
- (2) There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.

## 7 PIN CONFIGURATIONS



## PIN DESCRIPTION

PIN	NAME	I/O TYPE <sup>(1)</sup>	FUNCTION
<b>SOIC-14(SOP14)/TSSOP-14</b>			
1	1A	I	Channel 1 logic input
2	1B	I	Channel 1 logic input
3	1Y	O	Logic level output1
4	2A	I	Channel 2 logic input
5	2B	I	Channel 2 logic input
6	2Y	O	Logic level output2
7	GND	-	Ground
8	3Y	O	Logic level output3
9	3A	I	Channel 3 logic input
10	3B	I	Channel 3 logic input
11	4Y	O	Logic level output4
12	4A	I	Channel 4 logic input
13	4B	I	Channel 4 logic input
14	Vcc	-	Power Supply

(1) I=input, O=output.

## 8 SPECIFICATIONS

### 8.1 Absolute Maximum Ratings <sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup> <sup>(2)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	-0.5	6.5	V
V <sub>I</sub>	Input voltage range <sup>(2)</sup>	-0.5	6.5	V
V <sub>O</sub>	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>	-0.5	6.5	V
V <sub>O</sub>	Voltage range applied to any output in the high or low state <sup>(2)</sup> <sup>(3)</sup>	-0.5	V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> <0	-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> <0	-50	mA
I <sub>O</sub>	Continuous output current		±50	mA
	Continuous current through V <sub>CC</sub> or GND		±100	mA
θ <sub>JA</sub>	Package thermal impedance <sup>(4)</sup>	SOIC-14(SOP14)	104.5	°C/W
		TSSOP14	89.21	
T <sub>J</sub>	Junction temperature <sup>(5)</sup>	-65	150	°C
T <sub>stg</sub>	Storage temperature	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V<sub>CC</sub> is provided in the *Recommended Operating Conditions table*.
- (4) The package thermal impedance is calculated in accordance with JESD-51.
- (5) The maximum power dissipation is a function of T<sub>J(MAX)</sub>, R<sub>θJA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any ambient temperature is P<sub>D</sub> = (T<sub>J(MAX)</sub> - T<sub>A</sub>) / R<sub>θJA</sub>. All numbers apply for packages soldered directly onto a PCB.

### 8.2 ESD Ratings

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

		VALUE	UNIT
V <sub>(ESD)</sub> Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V
	Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup>	±1000	V
	Machine model (MM)	±200	V

- (1) JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process.



#### ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 9 ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (TYP values are at  $T_A = +25^\circ\text{C}$ , Full= $-40^\circ\text{C}$  to  $125^\circ\text{C}$ , unless otherwise noted.) <sup>(1)</sup>

### 9.1 Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Supply voltage	$V_{CC}$	Operating	2.0	5.5	V
High-level input voltage	$V_{IH}$	$V_{CC}=2.0\text{V}$	1.0		V
		$V_{CC}=3.3\text{V}$	1.5		
		$V_{CC}=4.5\text{V to }5.5\text{V}$	2.0		
Low-level input voltage	$V_{IL}$	$V_{CC}=2.0\text{V}$		0.3	V
		$V_{CC}=3.3\text{V}$		0.55	
		$V_{CC}=4.5\text{V to }5.5\text{V}$		0.8	
Input voltage	$V_I$		0	5.5	V
Output voltage	$V_O$		0	$V_{CC}$	V
Input transition rise or fall	$\Delta t/\Delta v$	$V_{CC}=2.0\text{V to }5.5\text{V}$		5	ns/V
Operating temperature	$T_A$		-40	+125	$^\circ\text{C}$

(1) All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation.

### 9.2 DC Characteristics

PARAMETER	TEST CONDITIONS	$V_{CC}$	TEMP	MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT
$V_{OH}$	$I_{OH} = -100\mu\text{A}$	2.0V to 5.5V	Full	$V_{CC}-0.1$			V
	$I_{OH} = -8\text{mA}$	2.0		1.6			
	$I_{OH} = -24\text{mA}$	3.3		2.5			
	$I_{OH} = -32\text{mA}$	4.5V		3.8			
		5V		4.2			
		5.5V		4.8			
$V_{OL}$	$I_{OL} = 100\mu\text{A}$	2.0V to 5.5V	Full			0.1	V
	$I_{OH} = 8\text{mA}$	2.0				0.45	
	$I_{OH} = 24\text{mA}$	3.3				0.55	
	$I_{OL} = 32\text{mA}$	4.5V				0.55	
		5V				0.5	
		5.5V				0.45	
$I_i$	A or B inputs	$V_i=5.5\text{V or GND}$	0V to 5.5V	+25 $^\circ\text{C}$	$\pm 0.1$	$\pm 1$	$\mu\text{A}$
				Full		$\pm 5$	
$I_{off}$	$V_I$ or $V_O=5.5\text{V}$	0V	+25 $^\circ\text{C}$	$\pm 0.1$	$\pm 1$	$\mu\text{A}$	
			Full		$\pm 10$		
$I_{CC}$	$V_i=5.5\text{V or GND, } I_o=0$	2.0V to 5.5V	+25 $^\circ\text{C}$	0.1	1	$\mu\text{A}$	
			Full		10		
ICCT	One input at 3.4V, Other inputs at $V_{CC}$ or GND	5.5V	Full			500	$\mu\text{A}$
$C_i$ (Input Capacitance)	$V_{CC}=0\text{V, } f=10\text{MHz}$	0V	+25 $^\circ\text{C}$		6		pF

(1) All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation.

(2) Limits are 100% production tested at 25 $^\circ\text{C}$ . Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.

(3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.

### 9.3 AC Characteristics

PARAMETER	SYMBOL	TEST CONDITIONS		MIN <sup>(2)</sup>	TYP <sup>(3)</sup>	MAX <sup>(2)</sup>	UNIT
Propagation Delay	t <sub>pd</sub>	V <sub>CC</sub> =2.0V±0.2V	C <sub>L</sub> =30pF, R <sub>L</sub> =500Ω		15.4		ns
		V <sub>CC</sub> =3.3V±0.3V	C <sub>L</sub> =50pF, R <sub>L</sub> =500Ω		13.3		
		V <sub>CC</sub> =5V±0.5 V	C <sub>L</sub> =50pF, R <sub>L</sub> =500Ω		4.4		
Power dissipation capacitance	C <sub>pd</sub>	V <sub>CC</sub> =5V	f=10MHz		22		pF

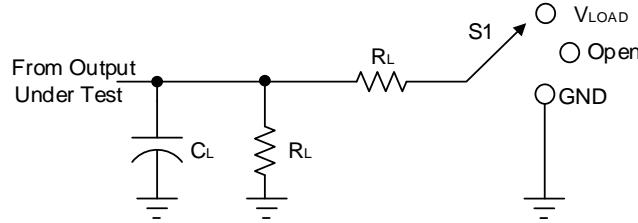
(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.

(2) This parameter is ensured by design and/or characterization and is not tested in production.

(3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.

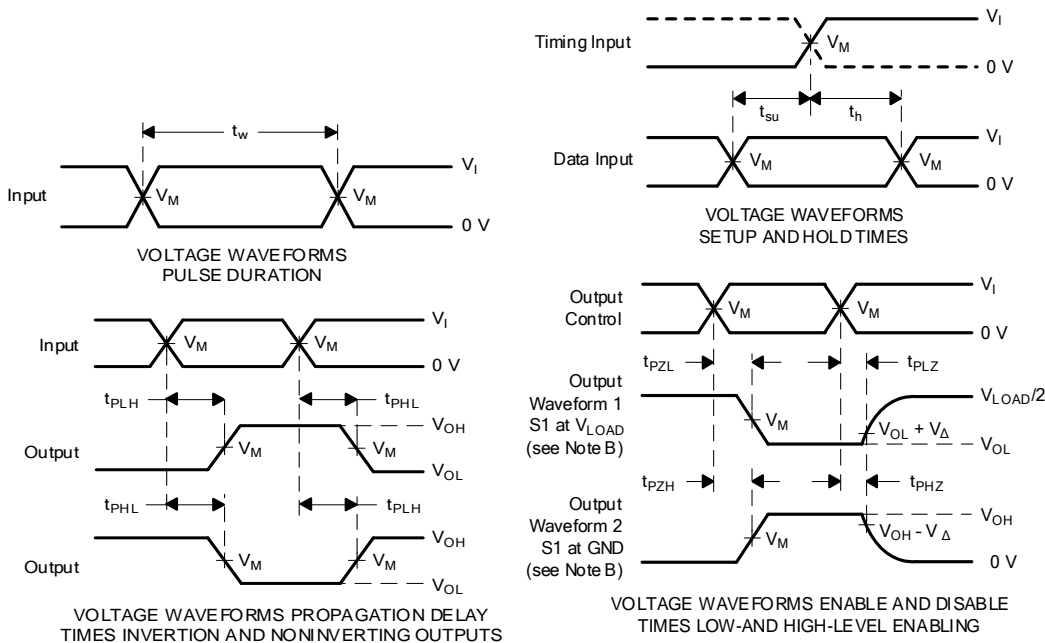


# 10 Parameter Measurement Information



TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND

$V_{CC}$	INPUTS		$V_M$	$V_{LOAD}$	CL		RL		$V_{\Delta}$
	$V_I$	$t_r/t_f$							
$1.8V \pm 0.15V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	30pF	1M $\Omega$	1k $\Omega$	0.15V
$2.5V \pm 0.2V$	$V_{CC}$	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	30pF	1M $\Omega$	500 $\Omega$	0.15V
$3.3V \pm 0.3V$	3V	$\leq 2.5ns$	1.5V	6V	15pF	50pF	1M $\Omega$	500 $\Omega$	0.3V
$5V \pm 0.5V$	$V_{CC}$	$\leq 2.5ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	50pF	1M $\Omega$	500 $\Omega$	0.3V



- NOTES: A. CL includes probe and jig capacitance.  
 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.  
 C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ .  
 D. The outputs are measured one at a time, with one transition per measurement.  
 E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .  
 F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .  
 G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .  
 H. All parameters and waveforms are not applicable to all devices.

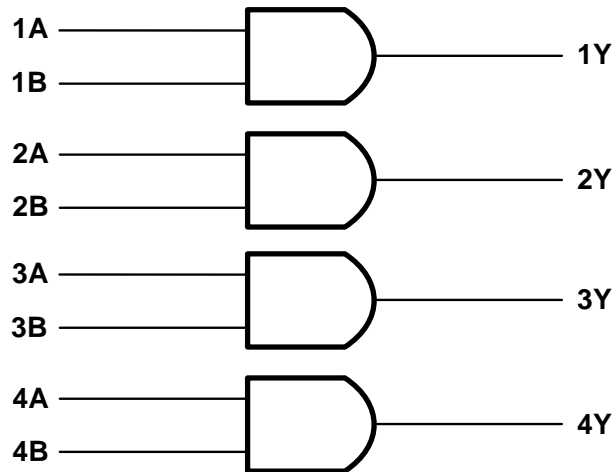
**Figure 1. Load Circuit and Voltage Waveforms**

## 11 Detailed Description

### 11.1 Overview

The RS4GT08 device is a quadruple 2-input positive-AND gate. The device performs the Boolean AND function ( $Y=A \cdot B$  or  $Y=\overline{\overline{A} + \overline{B}}$ ) in positive logic. Low  $I_{CC}$  current allows this device to be used in power sensitive or battery-powered applications. Robust inputs allow the device to up-translate with a propagation delay of 4.4 ns.

### 11.2 Functional Block Diagram



### 11.3 Feature Description

- The  $V_{CC}$  for the device is optimized at 5 V.
- The inputs accept  $V_{IH}$  levels of 2 V.
- Output ringing is minimized by slow edge rates.
- Inputs are TTL-Voltage compatible.

## 12 Application and Implementation

Information in the following applications sections is not part of the Runic component specification, and Runic does not warrant its accuracy or completeness. Runic's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 12.1 Application Information

The RS4GT08 device is quadruple AND gate, which is often used for many common functions like power sequencing or an on LED indicator. Because the device is configured to output LOW unless all inputs are HIGH, an LED tied to the output of the device will only turn HIGH when all systems connected are sending a HIGH, or ready signal.

### 12.2 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive also creates fast edges into light loads, so routing and load conditions must be considered to prevent ringing.

## 13 Power Supply Recommendations

The power supply pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1 $\mu$ F capacitor is recommended and if there are multiple  $V_{CC}$  terminals then 0.01 $\mu$ F or 0.022 $\mu$ F capacitors are recommended for each power terminal. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1 $\mu$ F and 1 $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible.

## 14 Layout

### 14.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally, they will be tied to GND or  $V_{CC}$  whichever make more sense or is more convenient.

### 14.2 Layout Example

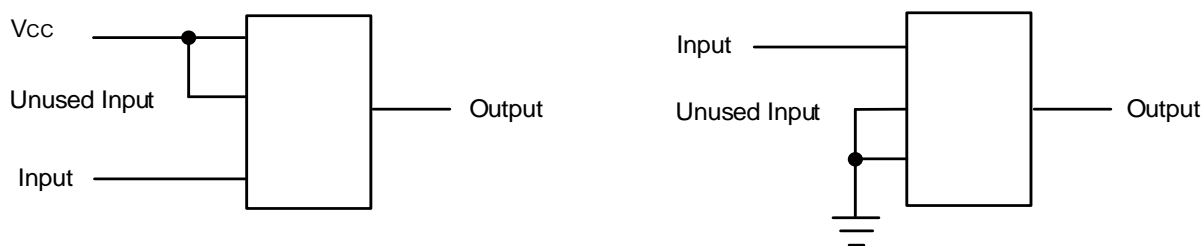
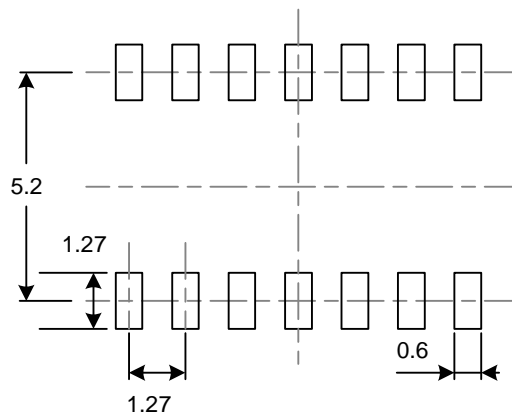
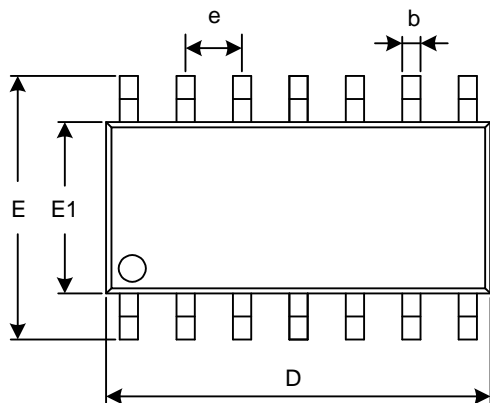


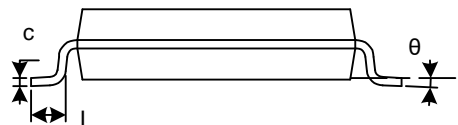
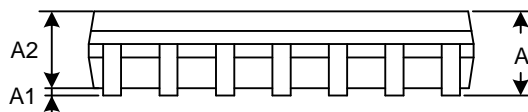
Figure 2. Layout Diagram

# 15 PACKAGE OUTLINE DIMENSIONS

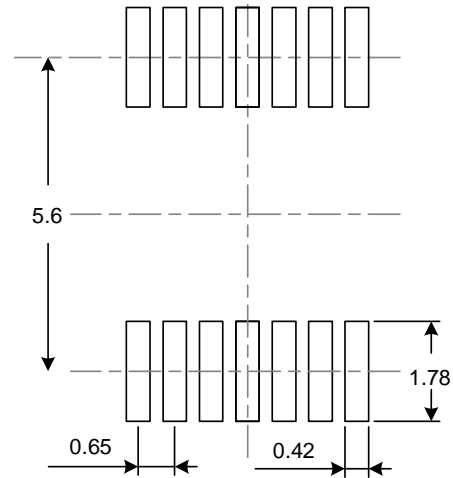
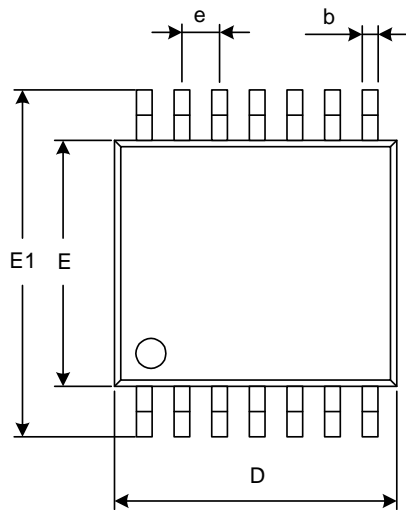
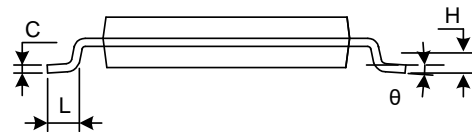
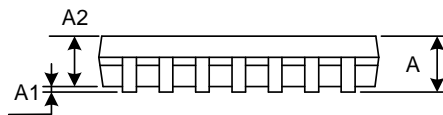
## SOIC-14(SOP14)



RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.310	0.510	0.012	0.020
c	0.100	0.250	0.004	0.010
D	8.450	8.850	0.333	0.348
e	1.270(BSC)		0.050(BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
$\theta$	0°	8°	0°	8°

**TSSOP-14**

**RECOMMENDED LAND PATTERN** (Unit: mm)


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	4.860	5.100	0.191	0.201
E	4.300	4.500	0.169	0.177
E1	6.250	6.550	0.246	0.258
e	0.650(BSC)		0.026(BSC)	
L	0.500	0.700	0.020	0.028
H	0.25(TYP)		0.01(TYP)	
$\theta$	1°	7°	1°	7°

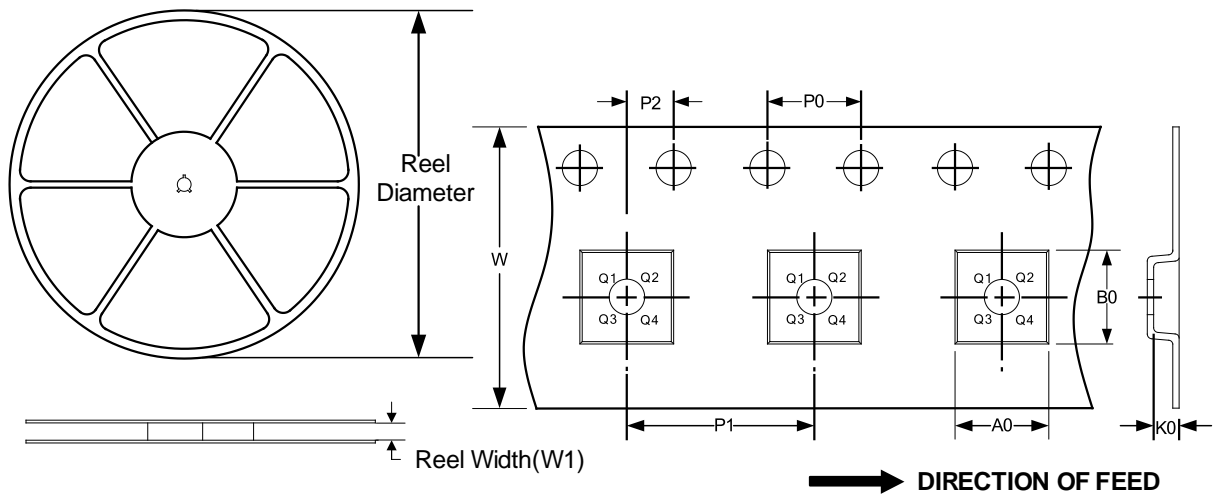
**NOTE:**

- A. All linear dimension is in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. BSC: Basic Dimension. Theoretically exact value shown without tolerances.

## 16 TAPE AND REEL INFORMATION

### REEL DIMENSIONS

### TAPE DIMENSION



NOTE: The picture is only for reference. Please make the object as the standard.

### KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width(mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-14(SOP14)	13"	16.4	6.60	9.30	2.10	4.0	8.0	2.0	16.0	Q1
TSSOP-14	13"	12.4	6.95	5.60	1.20	4.0	8.0	2.0	12.0	Q1

NOTE:

1. All dimensions are nominal.
2. Plastic or metal protrusions of 0.15mm maximum per side are not included.

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[NLV17SZ00DFT2G](#) [NLV17SZ126DFT2G](#) [NLV27WZ17DFT2G](#) [NLV74HC02ADR2G](#) [74HC32S14-13](#) [74LS133](#) [74LVC1G32Z-7](#)  
[74LVC1G86Z-7](#) [NLV74HC14ADR2G](#) [NLV74HC20ADR2G](#) [NLVVHC1G09DFT1G](#) [NLX2G86MUTCG](#) [74LVC2G32RA3-7](#)  
[74LVC2G00HD4-7](#) [NL17SG02P5T5G](#) [74LVC2G86HK3-7](#) [NLVVHC1G14DFT2G](#) [NLX1G99DMUTWG](#) [NLVVHC1G00DFT2G](#)  
[NLV7SZ57DFT2G](#) [NLV74VHC04DTR2G](#) [NLV27WZ00USG](#) [NLU1G86CMUTCG](#) [NLU1G08CMUTCG](#) [NL17SZ32P5T5G](#)  
[NL17SZ00P5T5G](#) [NL17SH02P5T5G](#) [74AUP2G00RA3-7](#) [NLVVHC1GT00DFT2G](#) [NLV74HC02ADTR2G](#) [NLX1G332CMUTCG](#)  
[NLVHCT132ADTR2G](#) [NL17SG86P5T5G](#) [NL17SZ05P5T5G](#) [NLV74VHC00DTR2G](#) [NLVVHC1G02DFT1G](#) [NLV74HC86ADR2G](#)  
[74LVC2G86RA3-7](#) [NL17SZ38DBVT1G](#) [NLV18SZ00DFT2G](#) [NLVVHC1G07DFT1G](#) [NLVVHC1G02DFT2G](#)